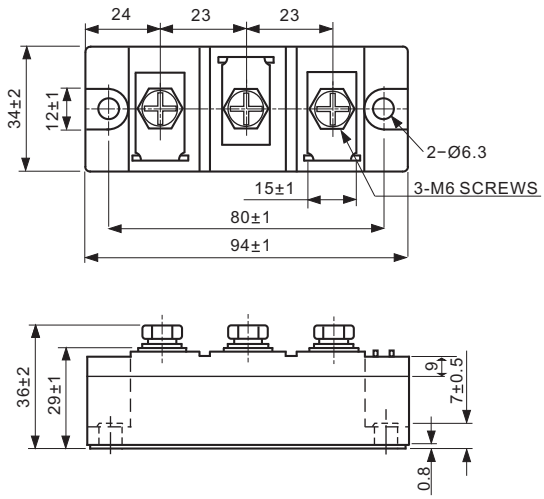
Standard Recovery Diodes, 200 A
(INT-A-PAK Power Modules)





All dimensions in millimeters

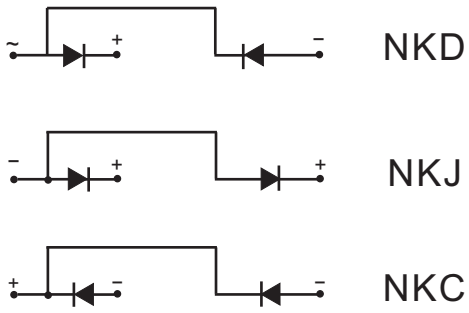
FEATURES

- High voltage
- Electrically isolated by DBC ceramic (Al_2O_3)
- 3000 V_{RMS} isolating voltage
- Industrial standard package
- High surge capability
- Glass passivated chips
- Modules uses high voltage power diodes in four basic configurations
- Simple mounting
- UL approved file E320098
- Compliant to RoHS
- Designed and qualified for multiple level

RoHS COMPLIANT

APPLICATIONS

- DC motor control and drives
- Battery charges
- Welders
- Power converters



PRODUCT SUMMARY	
$I_{F(AV)}$	200 A
Type	Modules - Diode, High Voltage

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	**CHARACTERISTICS**	**VALUE**	**UNITS**
$I_{F(AV)}$		200	A
	T_C	100	°C
$I_{F(RMS)}$		314	A
I_{FSM}	50 Hz	4870	
	60 Hz	5110	
I^2t	50 Hz	118	kA^2s
	60 Hz	108	
$I^2\sqrt{t}$		1186	$kA^2\sqrt{s}$
V_{RRM}		400 to 1600	V
T_J	Range	-40 to 150	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS

TYPE NUMBER	VOLTAGE CODE	V_{RRM}, MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM}, MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} AT 150 °C mA
NKD200 NKJ200 NKC200	04	400	500	12
	08	800	900	
	12	1200	1300	
	14	1400	1500	
	16	1600	1700	

FORWARD CONDUCTION

PARAMETER	SYMBOL	TEST CONDITIONS			VALUE	UNITS
Maximum average on-state current at case temperature	$I_{F(AV)}$	180° conduction, half sine wave			200	A
					100	°C
Maximum RMS on-state current	$I_{F(RMS)}$	180° conduction, half sine wave ,50Hz ,T_C = 100°C			314	A
Maximum peak, one-cycle, on-state non-repetitive surge current	I_{FSM}	t = 10 ms	No voltage reapplied	Sine half wave, initial T_J = T_J maximum	4870	
		t = 8.3 ms			5110	
Maximum I^2t for fusing	I^2t	t = 10 ms			118	kA^2s
		t = 8.3 ms			108	
		t = 10 ms	100%V_{RRM} reapplied		83	
		t = 8.3 ms			75.6	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	t = 0.1 ms to 10 ms, no voltage reapplied			1186	$kA^2\sqrt{s}$
Maximum forward voltage drop	V_{FM}	I_{FM} = 600A , T_J = 25 °C, 180° conduction			1.4	V

BLOCKING

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak reverse and off-state leakage current	I_{RRM}	T_J = 150 °C	12	mA
RMS isolation Voltage	V_{ISO}	50 Hz, circuit to base ,all terminals shorted ,t = 1s	3000	V
		t = 60s	2500	

THERMAL AND MECHANICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction operating temperature range	T_{Stg} , T_J		- 40 to 150	°C
Maximum thermal resistance, junction to ca se per junction	R_{thJC}	DC operation	0.21	°C/W
Maximum thermal resistance, case to heatsink per module	R_{thCS}	Mounting surface, smooth , flat and greased	0.075	
Mounting torque ± 10 % — IAP to heatsink, M6 / busbar to IAP, M6		A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound. Lubricated threads.	4 to 6	N.m
Approximate weight			220	g
			7.8	oz.
Case style			New INT-A-PAK	

Fig.1 On-state current vs. voltage characteristic

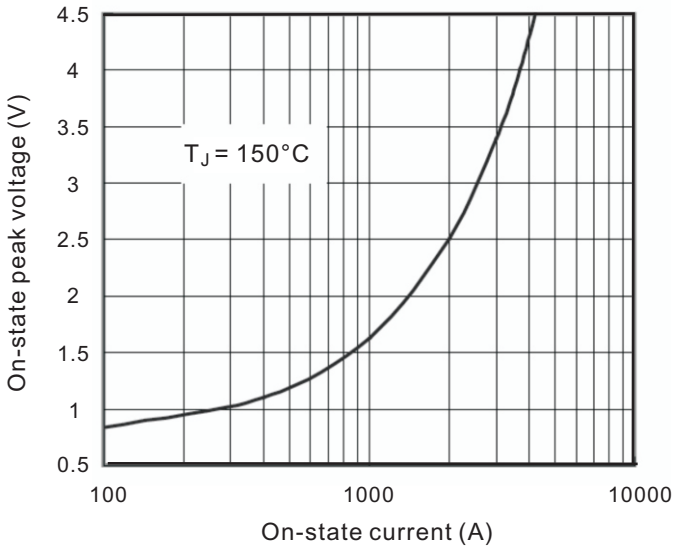


Fig.2 Transient thermal impedance(junction-case)

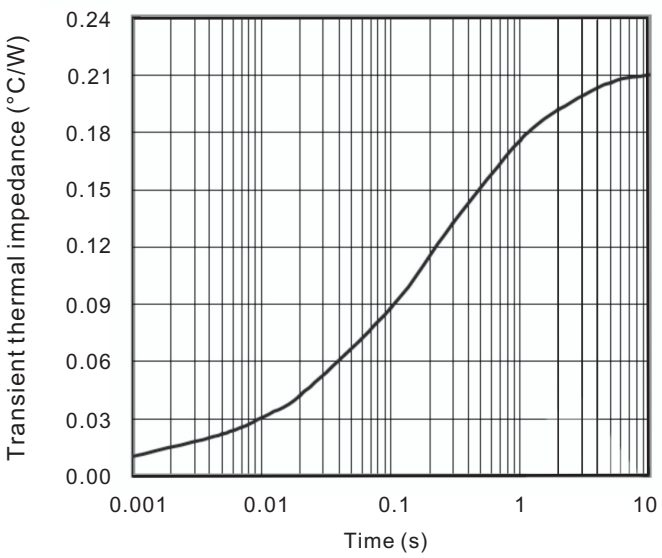


Fig.3 Power consumption vs. average current

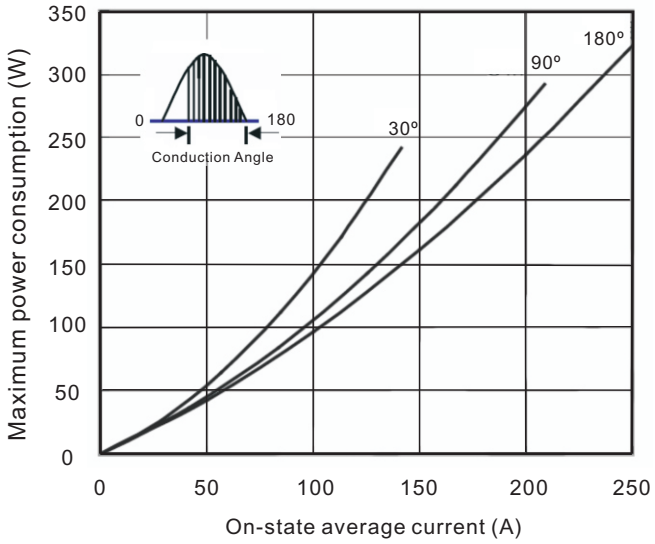


Fig.4 Case temperature vs. on-state average current

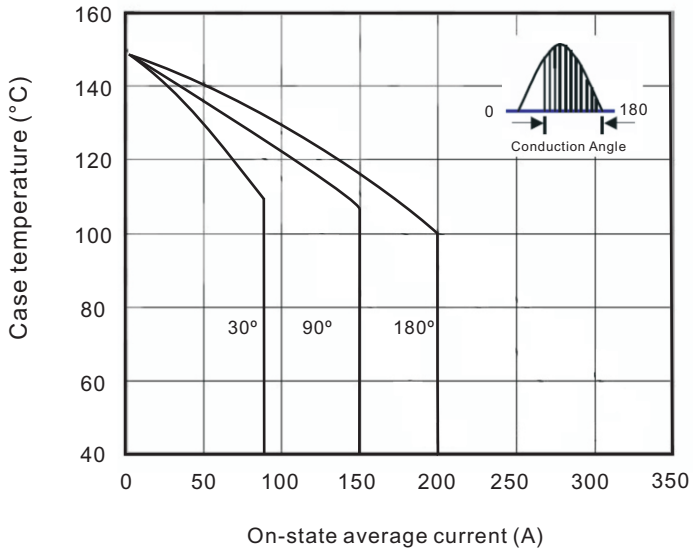


Fig.5 On-state surge current vs. cycles

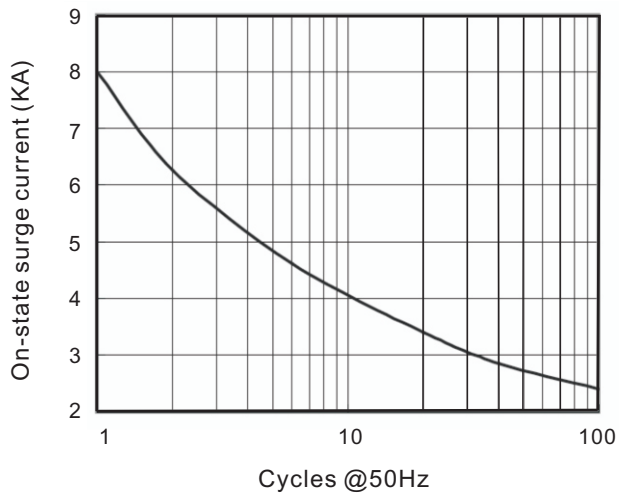


Fig.6 I^2t Characteristic

